

IWPSD 2021 (Main Program)

Day 1 – 14th December 2021, Tuesday

Time (IST)							
9:00	9:45	Inauguration- Hall 1					
9:45	10:45	Keynote Talk- Hall 1 (Common for all symposia)					
10:45	11:15	Tea Break					
11:15	13:00	Hall-1	Hall-2	Hall-3	Hall-4	Hall-5	Hall-6
		III-Nitrides: Materials and Devices (3N-SKN-1, 3N-I-1, 3N-I-2)	2D Materials and Devices (2D-SKN-1, 2D-I-1, 2D-I-2)	Device Simulations and Modeling (DSM-SKN-1, DSM-I-1, DSM-I-2)	Organic Semiconductors and Flexible Electronics (SID Co-Sponsored Symposium)	Semiconductor Devices for Quantum Technologies (QT-SKN-1, QT-I-1, QT-I-2)	Oxide Semiconductors and Devices (OS-SKN-1, OS-I-1, OS-I-2)
13:00	14:00	Lunch Break					
		Hall-1	Hall-2	Hall-3	Hall-4	Hall-5	Hall-6
		III-Nitrides: Materials and Devices (3N-I-3, 3N-I-4, 3N-I-5, 3N-O-1, 3N-O-2)	2D Materials and Devices (2D-SKN-2, 2D-I-3, 2D-I-4, 2D-O-1)	Device Simulations and Modeling (DSM-I-3, DSM-I-4, DSM-O-1, DSM-O-2, DSM-O-3)	Organic Semiconductors and Flexible Electronics (SID Co-Sponsored Symposium)	Semiconductor Devices for Quantum Technologies (QT-I-3, QT-I-4, QT-I-5, QT-O-1, QT-O-2)	Oxide Semiconductors and Devices (OS-I-3, OS-I-4, OS-I-5, OS-I-6)
16:00	16:15	Tea Break					
16:15	17:15	Industry Session- Hall 1					
17:15	18:00	Plenary Talk 1- Hall 1					
18:00	18:45	Plenary Talk 2- Hall 1					
End of Day-1							

Day 2 – 15th December 2021, Wednesday

Time (IST)							
9:30	10:15	Plenary Talk 3 - Hall 1					
10:15	11:00	Plenary Talk 4 - Hall 1					
11:00	11:15	Tea Break					
11.15	13:00	Hall-1	Hall-2	Hall-3	Hall-4	Hall-5	Hall-6
		III-Nitrides: Materials and Devices (3N-SKN-2, 3N-I-6, 3N-I-7)	2D Materials and Devices (2D-SKN-3, 2D-I-5, 2D-I-6)	Device Simulations and Modeling (DSM-SKN-2, DSM-I-5, DSM-O-4)	Organic Semiconductors and Flexible Electronics (OSFE-SKN-1, OSFE-I-1, OSFE-I-2)	Semiconductor Devices for Quantum Technologies (QT-SKN-2, QT-I-6, QT-I-7)	MEMS and NEMS Devices (MN-I-1, MN-I-2, MN-O-1, MN-O-2)
13:00	14:00	Lunch Break					
		Hall-1	Hall-2	Hall-3	Hall-4	Hall-5	Hall-6
		III-Nitrides: Materials and Devices (3N-SKN-3, 3N-I-8, 3N-I-9, 3N-O-3)	2D Materials and Devices (2D-I-7, 2D-I-8, 2D-I-9, 2D-O-2)	Photovoltaics and Energy Harvesting (PEH-I-1, PEH-I-2, PEH-I-3, PEH-O-1, PEH-O-2)	Organic Semiconductors and Flexible Electronics (OSFE-I-3, OSFE-I-4, OSFE-I-5, OSFE-I-6)	Semiconductor Crystal Growth, Epitaxy and Characterization (SC-SKN-1, SC-I-1, SC-I-2, SC-O-1, SC-I-3)	MEMS and NEMS Devices (MN-SKN-1, MN-I-3, MN-O-3, MN-O-4)
16:00	16:15	Tea Break					
16:15	18:00	Poster Session- E-Poster Hall					
18:00	19:00	Industry Session- Hall 1					
End of Day-2							

Day 3 – 16th December 2021, Thursday

Time (IST)							
9:30	10:15	Plenary Talk 5 - Hall 1					
10:15	11:00	Plenary Talk 6 - Hall 1					
11:00	11:15	Tea Break					
11.15	13:00	Hall-1	Hall-2	Hall-3	Hall-4	Hall-5	Hall-6
		III-Nitrides: Materials and Devices (3N-SKN-4, 3N-I-10, 3N-I-11)	2D Materials and Devices (2D-SKN-4, 2D-I-10, 2D-I-11)	Photovoltaics and Energy Harvesting (PEH-SKN-1, PEH-I-4, PEH-O-3)	Emerging Memory & Logic Devices for Storage and Computing (EM-SKN-1, EM-I-1, EM-I-2)	Semiconductor Crystal Growth, Epitaxy and Characterization (SC-SKN-2, SC-I-4, SC-I-5)	Compound Semiconductors (CS-SKN-1, CS-I-1, CS-I-2)
13:00	14:00	Lunch Break					
		Hall-1	Hall-2	Hall-3	Hall-4	Hall-5	Hall-6
		III-Nitrides: Materials and Devices (3N-I-12, 3N-I-13, 3N-I-14, 3N-O-4, 3N-O-5)	2D Materials and Devices (2D-I-12, 2D-I-13, 2D-I-14, 2D-O-3, 2D-O-4)	Photovoltaics and Energy Harvesting (PEH-I-5, PEH-I-6, PEH-O-4, PEH-O-5, PEH-O-6)	Emerging Memory & Logic Devices for Storage and Computing (EM-I-3, EM-I-4, EM-I-5, EM-I-6)	Semiconductor Crystal Growth, Epitaxy and Characterization (SC-SKN-3, SC-I-6, SC-I-7, SC-O-2)	MEMS/NEMS Devices (MN-I-4, MN-I-5, MN-I-6, MN-O-5, MN-O-6,)
16:00	16:15	Tea Break					
16:15	18:00	Poster Session- E-Poster Hall					
End of Day-3							

Day 4 – 17th December 2021, Friday

Time (IST)							
9:30	10:15	Plenary Talk 7 - Hall 1					
10:15	11:00	Plenary Talk 8 - Hall 1					
11:00	11:15	Tea Break					
		Hall-1	Hall-2	Hall-3	Hall-4	Hall-5	Hall-6
11.15	13:00		2D Materials and Devices (2D-I-15, 2D-I-16, 2D-O-5, 2D-O-6)		Emerging Memory & Logic Devices for Storage and Computing (EM-I-7, EM-I-8, EM-I-9, EM-I-10)	Semiconductor Devices for Quantum Technologies (QT-I-8, QT-I-9, QT-I-10)	Compound Semiconductors (CS-I-3, CS-I-4, CS-I-5)
13:00	13:30	Concluding Session- Hall 1					
End of Day-4							